

Using the TPS40193EVM-001

The TPS40193EVM-001 evaluation module is a 12V to 1.8V synchronous buck converter built around the <u>TPS40193</u> synchronous buck controller. This module provides a convenient test platform for both evaluating the TPS40193 controller in a real application and prototyping synchronous buck converters using the TPS40193 controller.

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1 Introduction

The TPS40193EVM-001 evaluation module (EVM) is a synchronous buck converter that provides a fixed 1.8V output at up to 10A from a 12V input bus. The EVM is designed to power up from a single supply, so no additional bias voltage is required for start-up. The demonstration module uses the TPS40193 reduced pin count mid-voltage synchronous buck controller.

1.1 Description

The TPS40193EVM-001 is designed to use a regulated 12V (8V–14V) bus to produce a regulated 1.8V output at up to 10A of load current. The EVM is designed to demonstrate the capabilities of the TPS40193 in a typical 12V bus to low-voltage application while providing a number of test points for evaluating the TPS40193 in a given application. The EVM can be modified to support output voltages from 0.9V to 3.3V by changing a single set resistor.

1.2 Applications

- Non-isolated medium current point-of-load and low voltage bus converters
- Networking equipment
- · Telecommunications equipment
- Computer peripherals
- Digital set-top box

1.3 Features

- 8V-14V input range
- 1.8V fixed output, adjustable with single resistor
- 10A dc steady state output current
- 300kHz switching frequency (fixed by TPS40193)
- Single SO-8 MOSFETs for both main switch and synchronous rectifier
- Double-sided, two active layer printed circuit board (PCB) with all components on top side
 - Test point signals routed on internal layers
- Active converter area of less than $1.2in^2(<1.54in \times 0.76in)$
- · Convenient test points for probing switching waveforms and non-invasive loop response testing



2 TPS40193EVM-001 Electrical Performance Specifications

Table 1 summarizes the electrical specifications of the TPS40193EVM-001.

Table 1. TPS40193EVM-001 Electrical and Performance Specifications

PARAMETER	SYMBOL	CONDITIONS	MIN	NOM	MAX	UNITS
Input Characteristics			1			
Input Voltage	V _{IN}		8	12	14	V
Input Current	I _{IN}	V _{IN} = Min, I _{OUT} = Max		2.7	2.85	Α
No Load Input Current		V _{IN} = Min, I _{OUT} = 0A		48	60	mA
Input UVLO	V _{IN_UVLO}	I _{OUT} = Min to Max	3.9	4.2	4.4	V
Input OV	V _{IN_OV}	I _{OUT} = Min to Max		N/A		V
Output Characteristics						
Output Voltage	V _{OUT}	V _{IN} = NOM, I _{OUT} = NOM	1.86	1.8	1.84	V
Line Regulation		V _{IN} = Min to Max, I _{OUT} = NOM			0.5	%
Load Regulation		V _{IN} = NOM, I _{OUT} = Min to Max			0.5	%
Output Voltage Ripple	V _{OUT_Ripple}	V _{IN} = NOM, I _{OUT} = MAX			40	mV_{PP}
Output Current	I _{OUT}	V _{IN} = Min to Max	0	6	10	Α
Output Over Current Inception Point	I _{OCP}	V _{IN} = NOM, V _{OUT} = (V _{OUT} - 5%)		19		А
Output OVP	V _{OVP}	I _{OUT} = Min to Max		N/A		V
Transient Response						
Load Step	ΔI	0.75 x I_{OUT_Max} to $0.25 \times I_{OUT_Max}$		5		Α
Load Slew Rate				5		A/μs
Overshoot					50	mV
Settling Time						ms
System Characteristics						
Switching Frequency	F _{SW}		250	300	350	kHz
Peak Efficiency	η_{PK}	V _{IN} = NOM, I _{OUT} = Min to Max		95		%
Full Load Efficiency	η	V _{IN} = NOM, I _{OUT} = Max		92		%
Operating Temperature Range	T _{OP}	V _{IN} = Min to Max, I _{OUT} = Min to Max	-40	+25	+60	°C
Mechanical Characteristics						
Dimensions	W	Width		1.54		in
(Active Area)	L	Length		0.76		in



3 Schematic

Figure 1 shows the schematic for this EVM. See Table 5, the Bill of Materials, for specific values.

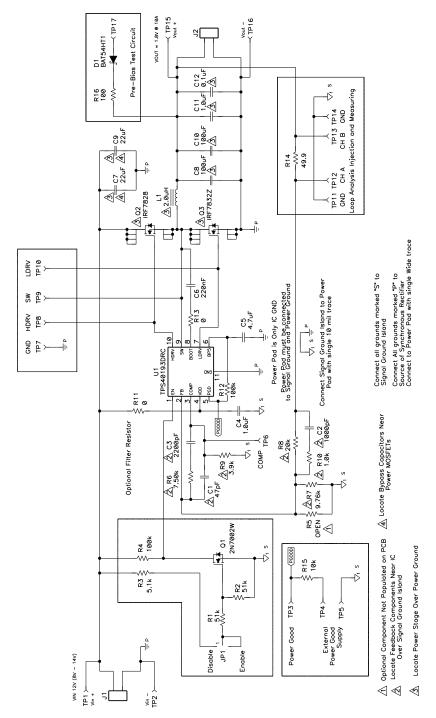


Figure 1. TPS40193EVM-001 Schematic



4 General Configuration and Description

This section reviews the general configurations for using the TPS40193EVM-001.

4.1 Adjusting Output Voltage (R7)

The regulated output voltage can be adjusted within a limited range by changing the ground resistor in the feedback resistor divider (R7). The output voltage is given by the formula shown in Equation 1:

$$V_{VOUT} = V_{VREF} \times \frac{R_8 + R_7}{R_7} \tag{1}$$

where:

- $V_{VREF} = 0.591V$ and
- $R_8 = 20k\Omega$

Table 2 contains common values for R7 to generate popular output voltages. The TPS40193EVM-001 is stable through these output voltages, but efficiency may suffer because the power stage is optimized for 1.8V output.

Table 2. Adjusting V_{OUT} with R7

V _{OUT}	R7 (kΩ)
3.3V	4.32
2.5V	6.19
2.25V	7.15
2.0V	8.25
1.8V	9.76
1.5V	13.0
1.2V	19.1
1.0V	28.7
0.9V	38.3

The values in Table 2 provide less than 1% nominal set-point error in the output voltage. If a tighter nominal value is required, R5 can be used in parallel with R7 to obtain a wider range of resistor values, using commonly-available E96 resistors.

4.2 Adjusting Short-Circuit Protection (R9)

The TPS40193 uses a selectable current limit for short-circuit protection. The current limit is selected from three predefined levels by placing a resistor at R9. The TPS40193 compares the voltage drop across the high-side FET (VDD to SW) to an internal reference voltage selected during start-up. Table 3 shows the voltage levels.

Table 3. Adjusting V_{SCP} with R9

V _{SCP} (min)	R7 (k Ω)
88mV	3.9
160mV	Open
228mV	12

The current before declaring short-circuit protection can be determined by dividing the V_{SCP} by the $R_{DS(ON)}$ of the high-side FET (Q2)



4.3 Disable Jumper (JP1)

The TPS40193EVM-001 provides a three-pin, 100mil (0.100in) header and shunt for testing the TPS40193 disable function.

Dis En

Placing the JP1 shunt in the Left Position JP1 drives the Q1 FET to pull the TPS40193 EN pin low,

disabling the controller. Removing the JP1 shunt or installing it in the Right Position shorts the Q1 gate to ground and enables the TPS40193EVM-001 output.

4.4 Test Point Descriptions

Table 4 describes the TPS40196EVM-001 test points and identifies the respective sections of this user quide that discuss each test point.

Test Point	Label	Use/Function	Section
TP1	V _{IN+}	Monitor input voltage to the module	Section 4.4.1
TP2	V _{IN} _	Monitor input voltage to the module	Section 4.4.1
TP3	Power-Good	Power-Good output voltage	
TP4	Ext Source	External source for Power-Good circuit	Section 4.4.2
TP5	GND	Ground for external source for Power-Good	0001011 4.4.2
TP6	COMP	Monitor COMP voltage	Section 4.4.3, Section 4.4.5
TP7	GND	Ground for SW, LDRV and HDRV measurements	
TP8	HDRV	Monitor high-side gate drive (Q2)	Section 4.4.4
TP9	SW	Monitor switch node waveforms	
TP10	LDRV	Monitor low-side gate drive (Q3)	
TP11	GND	Ground for Loop Monitoring Probe	
TP12	CH1	Loop injection point and injection monitoring point	Section 4.4.5
TP13	CH2	Loop injection point and output response monitoring point	Section 4.4.5
TP14	TP14 GND Ground for Loop Monitoring Probe		
TP15	TP15 V _{OUT+} Monitor output voltage from the module		Section 4.4.6
TP16	V _{OUT}	Monitor output voltage from the module	3ection 4.4.0
TP17	Pre-Bias	Injection point to test pre-bias load compliance	Section 4.4.7

Table 4. Test Point Descriptions

4.4.1 Input Voltage Monitoring (TP1, TP2)

The TPS40193EVM-001 provides two test points for measuring the voltage applied to the module. These test points allow the user to measure the actual module voltage without losses from input cables and connector losses. All input voltage measurements should be made between TP1 and TP2. To use TP1 and TP2, connect a voltmeter positive terminal to TP1 and negative terminal to TP2.



4.4.2 Power-Good (TP3, TP4, TP5)

The TPS40193EVM-001 has three test points to allow the user to evaluate the TPS40193 Power-Good function. TP4 provides access to the Power-Good output of the TPS40193. It has a $100k\Omega$ pull-up resistor to the TPS40193 5V regulator, and can be used as a logic signal with no additional requirements. TP3 provides a connection for an external power-good source for 3.3V logic. TP3 is connected to the power-good circuit through a $10k\Omega$ pull-up resistor. TP5 provides a local ground access to connect a remote disable circuit.

4.4.3 Compensation and Initialization (TP6)

The TPS40193EVM-001 also provides a test point connection to the COMP pin of the TPS40193 controller. This test point can be used to monitor the COMP voltage during the controller Power On Initialization that sets the controller short-circuit protection (SCP) threshold. The test point can also be used to monitor the pulse-width modulator (PWM) comparator input voltage (COMP) during operation, or used to measure the Power Stage Gain by following the Loop Analysis directions but moving Channel A probe from TP12 to TP6.

4.4.4 Switching Waveforms (TP7, TP8, TP9, TP10)

The TPS40193EVM-001 has three test points and a local ground connection (TP7) to monitor the main switching waveforms. Connect an oscilloscope probe to TP8 to monitor the high-side gate drive applied to the gate of Q2. Connect an oscilloscope probe to TP9 to monitor the switch node voltage. The gate-to-source voltage (V_{GS}) of the high-side FET can be determined by a math function TP8—TP9 if both channels use the same scale. Connect an oscilloscope probe to TP9 to monitor the low-side gate drive applied to the gate of Q3. Because the source of Q3 is connected directly to ground, no math function is required to determine the gate-to-source voltage of the low-side FET.

4.4.5 Loop Analysis (TP11, TP12, TP13, TP14)

The TPS40193EVM-001 contains a 49.9Ω series resistor (R14) in the feedback loop to allow for matched impedance signal injection into the feedback for loop response analysis. An isolation transformer should be used to apply a small (30mV or less) signal across R14 through TP12 and TP13. By monitoring the ac injection level at TP13 and the returned ac level at TP14, the power-supply loop response can be determined. Moving Channel A from TP12 to TP6 (COMP) the control-to-output response of the power stage (also referred to as the *power stage transfer function*) can be directly measured. See Section 3.9xx for a detailed procedure to perform loop response measurements.

4.4.6 Output Voltage and Monitoring (TP15, TP16)

There are two test points on the TPS40193EVM-001 for measuring the voltage generated by the module. These test points allow the user to measure the actual module output voltage without losses from output cables and connector losses. All output voltage measurements should be made between TP15 and TP16. To use TP1 and TP2, connect a voltmeter positive terminal to TP15 and negative terminal to TP16. For output ripple measurements, TP15 and TP16 allow a user to limit the ground loop area by using the tip and barrel measurement technique shown in Figure 3xx. (All output ripple measurements should be made using this method of measurement.)

4.4.7 Pre-Bias Input (TP17)

The TPS40193EVM-001 contains a pre-bias injection circuit with 100Ω resistor and series diode to allow testing and evaluation of the TPS40193 pre-bias support compatibility. Apply a voltage less than the target output voltage to TP17. Monitoring the output voltage during start-up demonstrates the ability of the TPS40193 to power up without drawing current from a pre-biased output. D2 prevents the output voltage from back-driving the pre-bias source.



5 Test Setup

5.1 Equipment

5.1.1 Voltage Source

 V_{IN} : The input voltage source (V_{IN}) should be a 0V–15V variable dc source capable of $5A_{DC}$. Connect V_{IN} to J1 as shown in Figure 2.

5.1.2 Meters

A1: 0A_{DC}-5A_{DC}, ammeter **V1:** V_{IN}, 0V-15V voltmeter **V2:** V_{OUT} 0V-5V voltmeter

5.1.3 Loads

LOAD1: The output load (LOAD1) should be an electronic constant current mode load capable of $0A_{DC}$ - $10A_{DC}$ at 1.8V.

5.1.4 Oscilloscope

Oscilloscope: A digital or analog oscilloscope can be used to measure the ripple voltage on V_{OUT} . The oscilloscope should be set for $1M\Omega$ impedance, 20MHz bandwidth, ac coupling, $1\mu s$ /division horizontal resolution, and 10mV/division vertical resolution for taking output ripple measurements. TP15 and TP16 can be used to measure the output ripple voltage by placing the oscilloscope probe tip through TP15 and holding the ground barrel to TP16, as shown in Figure 3. For a hands-free approach, the loop in TP16 can be cut and opened to cradle the probe barrel. Using a leaded ground connection may induce additional noise because of the large ground loop area.

5.1.5 Recommended Wire Gauge

 V_{IN} to J1: The connection between the source voltage, V_{IN} , and J1 of HPA238 can carry as much as 5A_{DC}. The minimum recommended wire size is AWG #16 with the total length of wire less than four feet (two feet input, two feet return max recommended).

J2 to LOAD1 (Power): The power connection between J2 of HPA238 and LOAD1 can carry as much as 10A_{DC}. The minimum recommended wire size is 2x AWG #16, with the total length of wire less than two feet (one foot output, one foot return max recommended).

5.1.6 Other

Fan: This evaluation module includes components that can become hot to the touch. Because this EVM is not enclosed (to allow probing of circuit nodes), a small fan capable of 200lfm–400lfm is required to reduce component surface temperatures to prevent user injury.

CAUTION

The EVM should not be left unattended while powered.

WARNING

The EVM should not be probed while the fan is not running.



5.2 Equipment Setup

Figure 2 through Figure 4 show the basic test setup recommended to evaluate the TPS40193EVM-001. Please note that although the return for J1 and J2 are the same, the connections should remain separate, as shown in Figure 2.

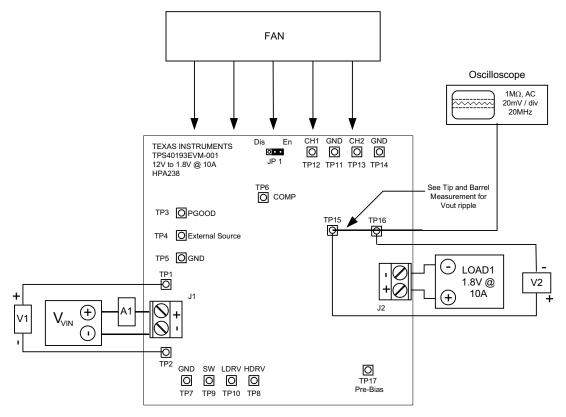


Figure 2. TPS40193EVM-001 Recommended Test Setup

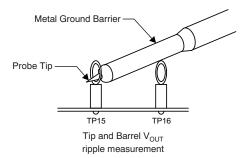


Figure 3. TPS40193EVM-001 Output Ripple Measurement—Tip and Barrel Using TP15 and TP16



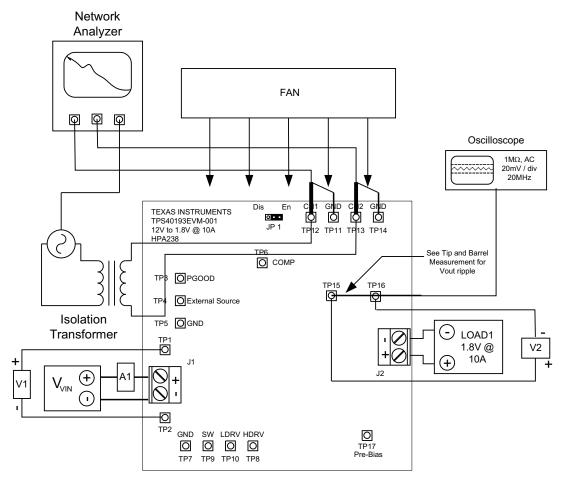


Figure 4. TPS40193EVM-001 Control Loop Measurement Setup

5.3 Start-up/Shutdown Procedure

Follow these steps to start up and shut down the TPS40193EVM-001.

- Step 1. Increase V_{IN} from 0V to 12 V_{DC} .
- Step 2. Vary LOAD1 from 0A_{DC} to 10A_{DC}.
- Step 3. Vary V_{IN} from 8.0V_{DC} to 14V_{DC}.
- Step 4. Decrease V_{IN} to $0V_{DC}$.
- Step 5. Decrease LOAD1 to 0A.

5.4 Output Ripple Voltage Measurement Procedure

Follow these steps to measure the output ripple voltage on the TPS40193EVM-001.

- Step 1. Increase V_{IN} from 0V to 12V_{DC}.
- Step 2. Adjust LOAD1 to desired load between 0A_{DC} and 10A_{DC}.
- Step 3. Adjust V_{IN} to desired load between $8.0V_{DC}$ and $14V_{DC}$.
- Step 4. Connect oscilloscope probe to TP15 and TP16 as shown in Figure 3.
- Step 5. Measure output ripple.
- Step 6. Decrease V_{IN} to 0V_{DC}.
- Step 7. Decrease LOAD1 to 0A.



5.5 Control Loop Gain and Phase Measurement Procedure

Follow these steps to measure the control loop gain and phase on the TPS40193EVM-001.

- Step 1. Connect 1kHz-1MHz isolation transformer to TP12 and TP13 as shown in Figure 4.
- Step 2. Connect input signal amplitude measurement probe (Channel A) to TP12 as shown in Figure 4.
- Step 3. Connect output signal amplitude measurement probe (Channel B) to TP13 as shown in Figure 4.
- Step 4. Connect ground lead of Channel A and Channel B to TP11 and TP14, as shown in Figure 4.
- Step 5. Inject 30mV (or less) signal across R14 through isolation transformer.
- Step 6. Sweep frequency from 1kHz to 1MHz, with 10Hz or lower post filter.
- Step 7. Control loop gain can be measured by Equation 2:

$$20 \times LOG \left[\frac{\text{Channel B}}{\text{Channel A}} \right]$$
 (2)

- Step 8. Control loop phase is measured by the phase difference between Channel A and Channel B.
- Step 9. Control to output response (power stage transfer function) can be measured by connecting Channel A probe to TP6 (COMP) and Channel B probe to TP13.
- Step 10. Output to control response (error amplifier transfer function) can be measured by connecting Channel B probe to TP6 (COMP) and Channel A probe to TP12
- Step 11. Disconnect isolation transformer from TP12 and TP13 before making other measurements (signal injection into feedback may interfere with accuracy of other measurements).

5.6 Equipment Shutdown

Follow these steps to power down the EVM.

- Step 1. Shut down oscilloscope.
- Step 2. Shut down V_{IN}.
- Step 3. Shut down LOAD1.
- Step 4. Shut down fan.

6 TPS40193EVM-001 Typical Performance Data and Characteristic Curves

Figure 5 through Figure 11 present typical performance curves for the TPS40193EVM-001. Since actual performance data can be affected by measurement techniques and environmental variables, these curves are presented for reference only and may differ from actual field measurements.

6.1 Efficiency

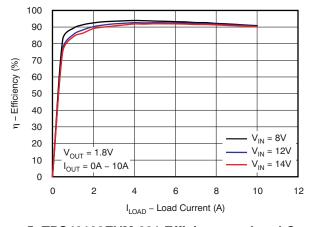


Figure 5. TPS40193EVM-001 Efficiency vs Load Current



6.2 Line and Load Regulation

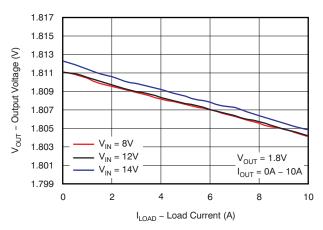


Figure 6. TPS40193EVM-001 Output Voltage vs Load Current ($\pm 0.5\%$ Window Shown)

6.3 Output Voltage Ripple

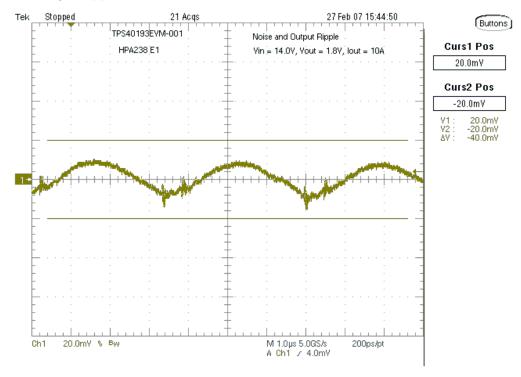
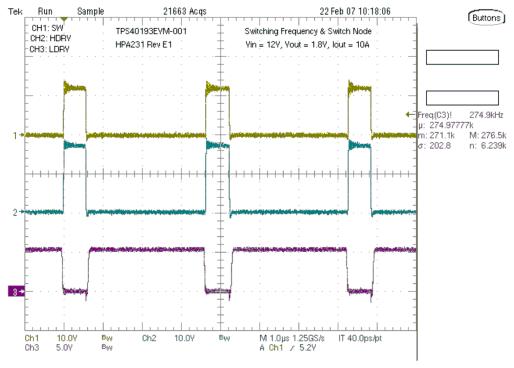


Figure 7. TPS40193EVM-001 Output Voltage Ripple

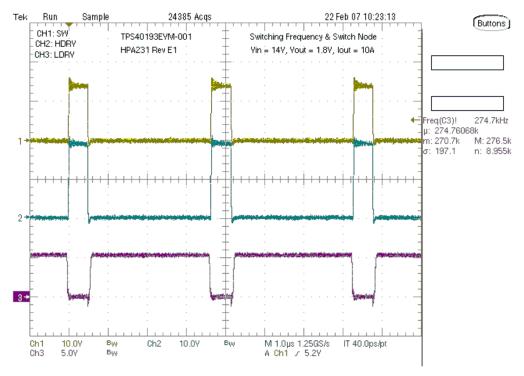


6.4 Switch Node



Ch1: TP9 (SW); Ch2: TP8 (HDRV); Ch3: TP10 (LDRV).

Figure 8. TPS40193EVM-001 Switching Waveforms ($V_{IN} = 8V$, $I_{OUT} = 10A$)



Ch1: TP9 (SW); Ch2: TP8 (HDRV); Ch3: TP10 (LDRV).

Figure 9. TPS40193EVM-001 Switching Waveforms (V_{IN} = 14V, I_{OUT} = 10A)



6.5 Control Loop Bode Plot

6.5.1 Low Line $(V_{IN} = 8V)$

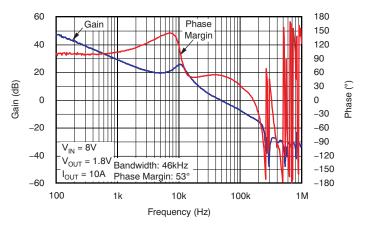


Figure 10. TPS40193EVM-001 Gain and Phase vs Frequency

6.5.2 High Line $(V_{IN} = 14V)$

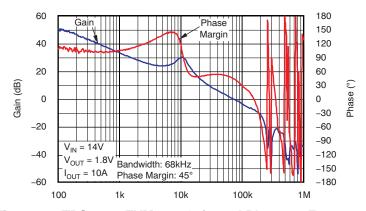


Figure 11. TPS40193EVM-001 Gain and Phase vs Frequency

7 EVM Assembly Drawings and Layout

Figure 12 through Figure 17 show the design of the TPS40193EVM-001 printed circuit board (PCB). The EVM has been designed using a 4-layer, 2oz., copper-clad PCB (2.5in x 2.5in), with all components in a 1.54in x 0.76in active area on the top side and all active traces to the top and bottom layers of the board. This configuration allows the user to easily view, probe and evaluate the TPS40193 control IC in a practical, double-sided application. Moving components to both sides of the PCB or using additional internal layers can offer additional size reduction for space-constrained systems.

Unless otherwise specified, these figures illustrate the view from the top side of the PCB.

Note: Board layouts are not to scale. These figures are intended to show how the board is laid out; they are not intended to be used for manufacturing TPS40193EVM-001 PCBs.



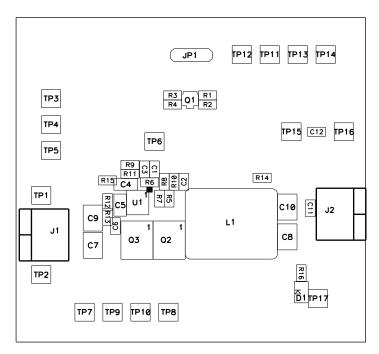


Figure 12. TPS40193EVM-001 Component Placement

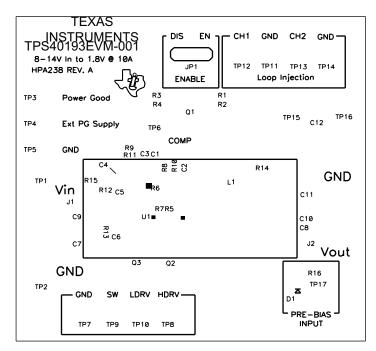


Figure 13. TPS40193EVM-001 Silkscreen



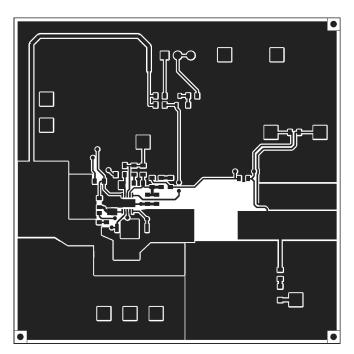


Figure 14. TPS40193EVM-001 Top Copper Layer

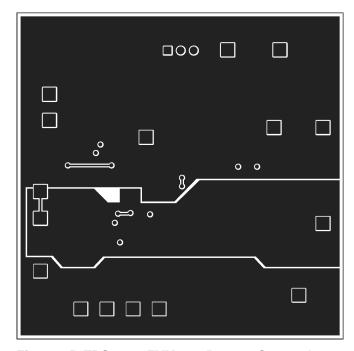


Figure 15. TPS40193EVM-001 Bottom Copper Layer



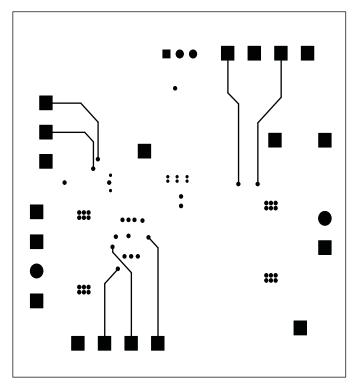


Figure 16. TPS40193EVM-001 Internal Layer 1

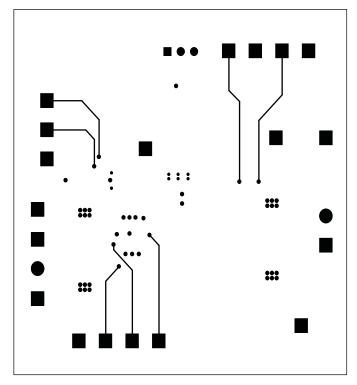


Figure 17. TPS40193EVM-001 Internal Layer 2



8 Bill of Materials

Table 5 lists the EVM components as configured according to the schematic (see Figure 1).

Table 5. Bill of Materials

2 J1, J2 ED1609-ND Terminal Block, 2-pin, 15-A, 5.1mm 0.40in x 0.35in ED1609 OS 1 JP1 PTC36SAAN Header, 3-pin, 100mil spacing, (36-pin strip) 0.100in x 3in PTC36SAAN Su 1 L1 2 Inductor, SMT, xxA 0.512in x 0.571in PG0077.xxx Pu 1 Q1 2N7002W Mosfet, N-Ch, VDS 60v, RDS 2 ohms, ID SOT-323 (SC-70) 2N7002W-7 Dic 1 Q2** IRF7828 XSTR, MOSFET, N-Chan, 30V, Rds(ON) SO8 IRF7828 IR 1 Q3** IRF7832Z XSTR, MOSFET, N-Chan, 30V, Rds(ON) SO8 IRF7832Z IR 2 R1, R2 51k Resistor, Chip, 1/16W, 5% 0603 Std Std 2 R1, R1 1.0k Resistor, Chip, 1/16W, 5% 0603 Std Std 1 R12 100k Resistor, Chip, 1/16W, 5% 0603 Std Std 1 R12 100k Resistor, Chip, 1/16W, 5% 0603 Std Std <	MFR
C12	.TD
C2	. D
1 C3 2200pF Capacitor, Ceramic, 10V, C0G, 10% 0603 STD ST 1 C4 1.0µF Capacitor, Ceramic, 28V, X5R, 20% 0805 STD ST 1 C5 4.7µF Capacitor, Ceramic, 10V, X5R, 20% 0805 STD ST 1 C6 220nF Capacitor, Ceramic, 10V, X5R, 20% 0603 Std Std 2 C7, C9 22µF Capacitor, Ceramic, 25V, X5R, 20% 1210 C3225X7R1E1 TD 1 D2 BAT54HT1 Diode, Schottky, 200-mA, 30-V SOD323 BAT54HT1 On 6M 2 J1, J2 ED1609-ND Terminal Block, 2-pin, 15-A, 5.1mm 0.40in x 0.35in ED1609 OS 1 JP1 PTC36SAAN Header, 3-pin, 100mil spacing, (36-pin strip) 0.10in x 3in PTC36SAAN PU 1 JP1 PTC36SAAN Header, 3-pin, 100mil spacing, (36-pin strip) 0.10in x 3in PTC36SAAN PU 1 JP1 PTC36SAAN Header, 3-pin, 100mil spacing, (36-pin strip) 0.10in x 3in	. D
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TP15, TP17	d
C TD2 TD5 F044 Tost Point Plack Thrullala 0.405in v.0.405in F044	eystone
6 TP2, TP5, TP7, TP11, TP14, TP16 Test Point, Black, Thru Hole 0.125in x 0.125in 5011 Ke	eystone
7 TP3, TP6, TP8, TP9, TP10, TP12, TP13 Test Point, White, Thru Hole 0.125in x 0.125in 5012 Ke	eystone
	exas struments
1 — PCB, 3 ln x 3 ln x 0.062 ln — HPA238 An	ıy
1 — Shunt, 100-mil, Black 0.100 929950-00 3M	1

EVALUATION BOARD/KIT IMPORTANT NOTICE

Texas Instruments (TI) provides the enclosed product(s) under the following conditions:

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EVM WARNINGS AND RESTRICTIONS

It is important to operate this EVM within the input voltage range of 4.5V to 18V and the output voltage range of 0.6V to 5.0V.

Exceeding the specified input range may cause unexpected operation and/or irreversible damage to the EVM. If there are questions concerning the input range, please contact a TI field representative prior to connecting the input power.

Applying loads outside of the specified output range may result in unintended operation and/or possible permanent damage to the EVM. Please consult the EVM User's Guide prior to connecting any load to the EVM output. If there is uncertainty as to the load specification, please contact a TI field representative.

During normal operation, some circuit components may have case temperatures greater than +40°C. The EVM is designed to operate properly with certain components above +40°C as long as the input and output ranges are maintained. These components include but are not limited to linear regulators, switching transistors, pass transistors, and current sense resistors. These types of devices can be identified using the EVM schematic located in the EVM User's Guide. When placing measurement probes near these devices during operation, please be aware that these devices may be very warm to the touch.

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